

3A, 400V - 600V Super Fast Rectifier

FEATURES

- High efficiency, Low V_F
- High current capability
- · High surge current capability
- Low power loss
- RoHS Compliant
- Halogen-free according to IEC 61249-2-21

APPLICATIONS

- DC to DC converter
- Switching mode converters and inverters
- Freewheeling application

MECHANICAL DATA

- Case: DO-201AD
- Molding compound meets UL 94V-0 flammability rating
- Terminal: Pure tin plated leads, solderable per J-STD-002
- Meet JESD 201 class 1A whisker test
- · Polarity: Indicated by cathode band
- Weight: 1.20g (approximately)

KEY PARAMETERS			
PARAMETER VALUE U			
I _F	3	А	
V_{RRM}	400 - 600	V	
I _{FSM}	45	Α	
T_{JMAX}	150	°C	
Package	DO-201AD		
Configuration	Single die		







ABSOLUTE MAXIMUM RATINGS (T _A = 25°C unless otherwise noted)					
PARAMETER	SYMBOL	31DF4	31DF6	UNIT	
Marking code on the device		31DF4	31DF6		
Repetitive peak reverse voltage	V_{RRM}	400	600	V	
Reverse voltage, total rms value	$V_{R(RMS)}$	280	420	V	
Forward current	I _F	3		А	
Surge peak forward current, 8.3ms single half sine wave superimposed on rated load	I _{FSM}	45		А	
Junction temperature	TJ	-55 to +150		°C	
Storage temperature	T _{STG}	-55 to +150		°C	



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THERMAL PERFORMANCE				
PARAMETER	SYMBOL	TYP	UNIT	
Junction-to-ambient thermal resistance	R _{eJA}	80	°C/W	

ELECTRICAL SPECIFICATIONS (T _A = 25°C unless otherwise noted)					
PARAMETER	CONDITIONS	SYMBOL	TYP	MAX	UNIT
Forward voltage ⁽¹⁾	I _F = 3A, T _J = 25°C	V _F		1.7	V
Reverse current @ rated V _R ⁽²⁾	T _J = 25°C	I _R	-	20	μΑ
	T _J = 125°C		-	100	μΑ
Reverse recovery time	$I_F = 0.5A, I_R = 1.0A,$ $I_{rr} = 0.25A$	t _{rr}	-	35	ns

Notes:

- 1. Pulse test with PW = 0.3ms
- 2. Pulse test with PW = 30ms

ORDERING INFORMATION				
ORDERING CODE ⁽¹⁾	PACKAGE	PACKING		
31DFx	DO-201AD	1,250 / Tape & Reel		
31DFx A0G	DO-201AD	500 / Ammo box		

Notes:

1. "x" defines voltage from 400V (31DF4) to 600V (31DF6)



CHARACTERISTICS CURVES

(T_A = 25°C unless otherwise noted)

Fig.1 Forward Current Derating Curve

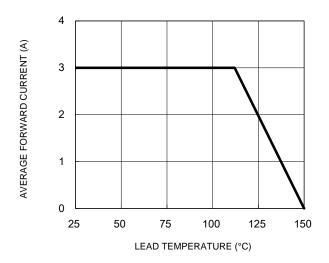


Fig.3 Typical Reverse Characteristics

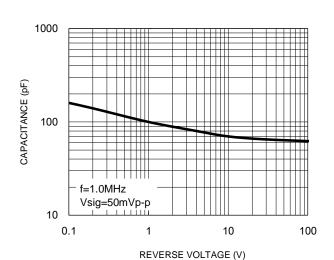
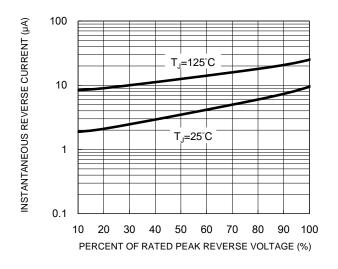


Fig.2 Typical Junction Capacitance

Fig.4 Typical Forward Characteristics



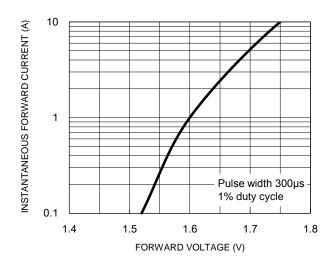
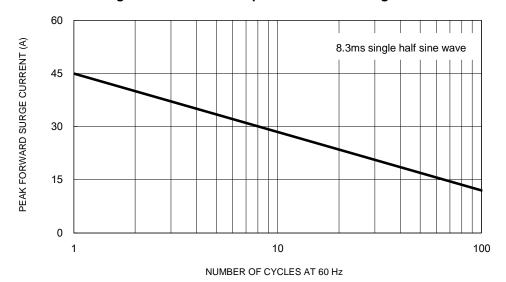


Fig.5 Maximum Non-Repetitive Forward Surge Current



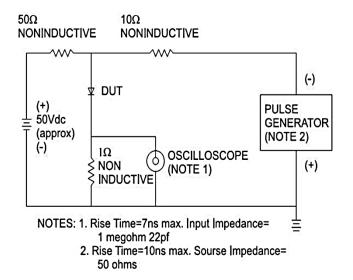


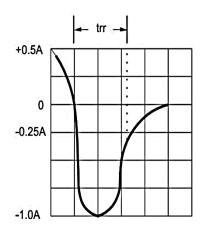
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CHARACTERISTICS CURVES

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$

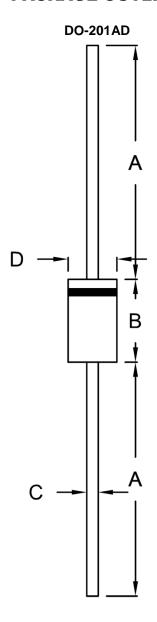
Fig.6 Reverse Recovery Time Characteristic and Test Circuit Diagram







PACKAGE OUTLINE DIMENSIONS



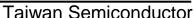
DIM	OIM. Unit (mm) Min. Max.		Unit (inch)		
Dilvi.			Min.	Max.	
А	25.40	-	1.000	-	
В	8.50	9.50	0.335	0.374	
С	1.20	1.30	0.047	0.051	
D	5.00	5.60	0.197	0.220	

MARKING DIAGRAM



= Marking Code P/N G = Green Compound

YWW = Date Code = Factory Code F





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